

XC74UL02AA



CMOS Logic

- ◆ CMOS 2-Input NOR Gate
- ◆ High Speed Operation : tpd = 2.65ns (TYP.)
- ◆ Operating Voltage Range : 2V ~ 5.5V
- ◆ Low Power Consumption : 1μ A (MAX.)

■ APPLICATIONS

- Palmtops
- Digital equipment

■ GENERAL DESCRIPTION

The XC74UL02AA is a 2-input CMOS NOR Gate, manufactured using silicon gate CMOS fabrication.

CMOS low power circuit operation makes high speed LS-TTL operation achievable.

With a wave forming buffer connected internally, stabilized output can be achieved as the circuit offers high noise immunity.

As the XC74UL02AA is integrated into mini molded, SSOT-25 and SOT-25 packages, high density mounting is possible.

■ FEATURES

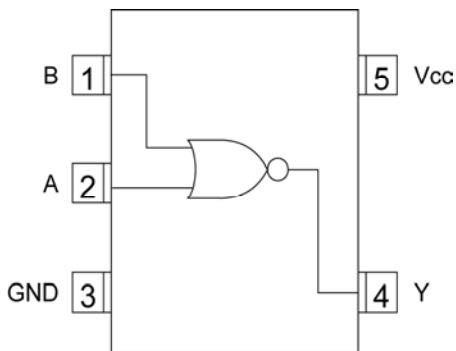
High Speed Operation : tpd = 2.65ns (TYP.)

Operating Voltage Range : 2V ~ 5.5V

Low Power Consumption: 1μ A (MAX.)

Ultra Small Packages : SSOT-25 and SOT-25

■ PIN CONFIGURATION



SSOT-25/SOT-25
(TOP VIEW)

■ FUNCTIONS

INPUT		OUTPUT
A	B	Y
L	L	H
L	H	L
H	L	L
H	H	L

H=High level

L=Low level

■ ABSOLUTE MAXIMUM RATINGS

Ta=-40°C~85°C

PARAMETER	SYMBOL	RATINGS	UNITS
Supply Voltage	VCC	-0.5~+6.0	V
Input Voltage	VIN	-0.5~+6.0	V
Output Voltage	VOUT	-0.5~VCC+0.5	V
Input Diode Current	I _{IK}	-20	mA
Output Diode Current	I _{OK}	± 20	mA
Output Current	I _{OUT}	± 25	mA
VCC,GND Current	I _{CC} ,I _{GND}	± 50	mA
Power Dissipation(Ta=55°C)	P _d	150	mW
Storage Temperature Range	T _{stg}	-65~+150	°C

* Voltage is all ground standardized.

XC74UL02AA

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	V _{CC} (V)	CONDITIONS	UNITS
Supply Voltage	V _{CC}	-	2~5.5	V
Input Voltage	V _{IN}	-	0~5.5	V
Output Voltage	V _{OUT}	-	0~V _{CC}	V
Operating Temperature Range	T _{opr}	-	-40~+85	°C
Output Current	I _{OH}	3.0	-4	mA
		4.5	-8	
	I _{OL}	3.0	4	
		4.5	8	
Input Rise and Fall Time	t _{r,tf}	3.3	0~100	ns
		5.0	0~20	

DC ELECTRICAL CHARACTERISTICS

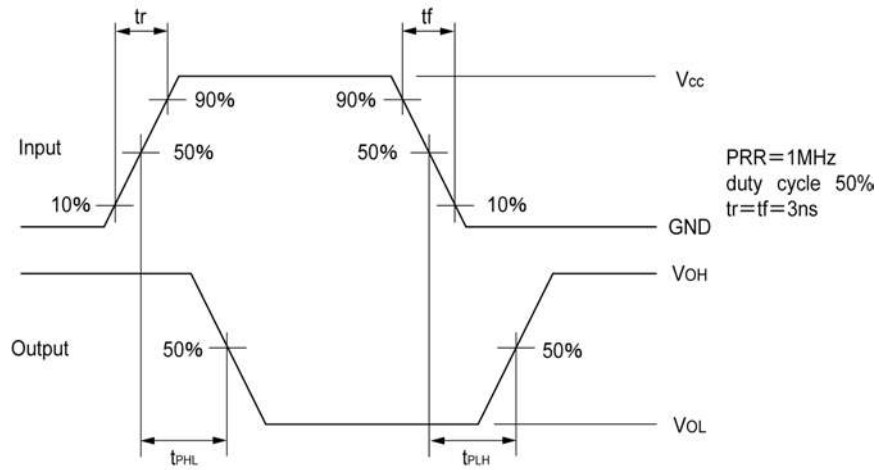
PARAMETER	SYMBOL	V _{CC} (V)	CONDITIONS	Ta=25°C			Ta=-40°C~85°C		UNITS	
				MIN.	TYP.	MAX.	MIN.	MAX.		
Input Voltage	V _{IH}	2.0		1.5	-	-	1.5	-	V	
		3.0		2.1	-	-	2.1	-		
		5.5		3.85	-	-	3.85	-		
	V _{IL}	2.0		-	-	0.5	-	0.5	V	
		3.0		-	-	0.9	-	0.9		
		5.5		-	-	1.65	-	1.65		
Output Voltage	V _{OH}	2.0	V _{IN} =V _{IH}	I _{OH} =-50μ A	1.9	2.0	-	1.9	-	V
		3.0			2.9	3.0	-	2.9	-	
		4.5		4.4	4.5	-	4.4	-		
		3.0		I _{OH} =-4mA	2.58	-	-	2.48	-	
		4.5			I _{OH} =-8mA	3.94	-	-	3.80	
	V _{OL}	2.0	V _{IN} =V _{IH}	I _{OL} =50μ A		-	-	0.1	-	0.1
		3.0			-	-	0.1	-	0.1	
		4.5			-	-	0.1	-	0.1	
		3.0		I _{OL} =4mA	-	-	0.36	-	0.44	
		4.5			I _{OL} =8mA	-	-	0.36	-	0.44
Input Current	I _{IN}	0~5.5	V _{IN} =V _{CC} or GND	-0.1		-	0.1	-1.0	1.0	μ A
Static Supply Current	I _{CC}	5.5	V _{IN} =V _{CC} or GND, I _{OUT} =0μ A	-	-	1.0	-	10.0		

SWITCHING ELECTRICAL CHARACTERISTICS

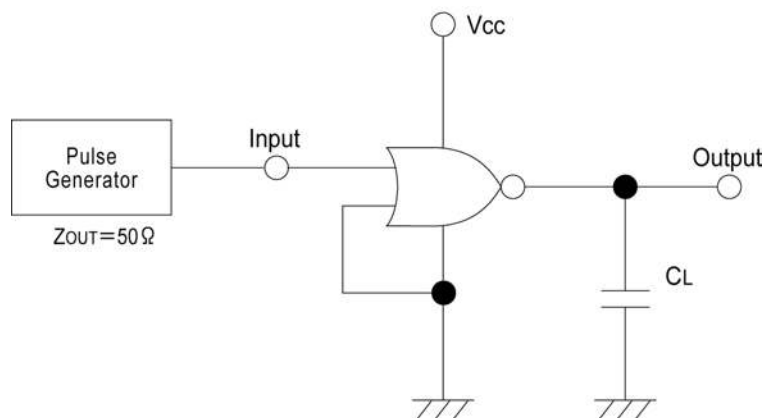
t_r=t_f=3ns

PARAMETER	SYMBOL	C _L	V _{CC} (V)	CONDITIONS	Ta=25°C			Ta=-40°C~85°C		UNITS
					MIN.	TYP.	MAX.	MIN.	MAX.	
Delay Time	t _{PLH}	15pF	3.3		-	3.9	7.9	1.0	9.5	ns
			5.0		-	2.7	5.5	1.0	6.5	
		50pF	3.3		-	5.5	11.4	1.0	13.0	ns
			5.0		-	3.9	7.5	1.0	8.5	
	t _{PHL}	15pF	3.3		-	3.5	7.9	1.0	9.5	ns
			5.0		-	2.6	5.5	1.0	6.5	
		50pF	3.3		-	4.9	11.4	1.0	13.0	ns
			5.0		-	3.6	7.5	1.0	8.5	
Input Capacitance	C _{IN}	-	5.0	V _{IN} =V _{CC} or GND	-	4	10	-	10	pF
Power Dissipation Capacitance	C _{pd}	No Load, f=1MHz			-	9.7	-	-	-	pF

■ WAVEFORM



■ TEST CIRCUIT



Note: Open output when measuring supply current